

Національна академія наук України
Інститут проблем реєстрації інформації
Ужгородська лабораторія матеріалів оптоелектроніки та фотоніки Інституту
проблем реєстрації інформації
Технічний центр
Ужгородський національний університет

Школа-конференція молодих вчених

СУЧАСНЕ МАТЕРІАЛОЗНАВСТВО: ФІЗИКА, ХІМІЯ, ТЕХНОЛОГІЇ
(СМФХТ – 2021)

**Ужгород Водограй Україна,
4 - 8 жовтня 2021р.**

**ПРОГРАМА ТА
МАТЕРІАЛИ КОНФЕРЕНЦІЇ**

ЕЛЕКТРОННА ВЕРСІЯ

**Ужгород
2021**

УДК 536:669
ББК 34

РЕДКОЛЕГІЯ

ГОЛОВНИЙ РЕДАКТОР

Наумовець А.Г.

ЧЛЕНИ РЕДАКЦІЙНОЇ РАДИ

Беспалов С.А., Мальчевський І.А., Поп М.М., Рубіш В.М.

ЗАСТУПНИКИ ГОЛОВНОГО РЕДАКТОРА

Крючин А.А. Уваров В.М.

Друкується за рішенням Оргкомітету СМФХТ–2021 і Вченої ради Інституту проблем реєстрації інформації НАН України

Матеріали Школи-конференції молодих вчених «Сучасне матеріалознавство: фізика, хімія, технології (СМФХТ – 2021)» – Ужгород: ФОП Сабов А.М., Україна – 320 с.

Матеріали відображають зміст лекцій вітчизняних та європейських науковців у галузі фізики, хімії та технології нових функціональних матеріалів та доповідей конференції за результатами фундаментальних та прикладних науково-дослідних робіт з актуальних питань в області сучасного матеріалознавства за різними напрямками: метали, сплави, кераміка і композиційні матеріали; напівпровідникові, діелектричні, магнітні та склоподібні матеріали; наносистеми, наноматеріали, нанотехнології; розмірні ефекти, самоорганізація і моделювання наноструктур; плівки, покриття і поверхневі наносистеми; біофункціональні наноматеріали, наносистеми в біології та медицині; полімери, супрамолекулярні структури, колоїдні системи, аерогелі; технологія, діагностика та застосування матеріалів різноманітного призначення.

Видання розраховано на наукових працівників, інженерів, викладачів вузів, аспірантів і студентів відповідних спеціальностей.

Організаційний комітет

Голова:

Наумовець А.Г. (Київ, Україна)

Заступники голови:

Крючин А.А. (Київ, Україна)

Уваров В.М. (Київ, Україна)

Вчений секретар:

Рубіш В.М. (Ужгород, Україна)

Беляєв О.Є., Беспалов С.А., Бродін М.С., Воєводін В.М., Височанський Ю.М., Картель М.Т.,
Кладько В.П., Комісаренко С.В., Кошечко В.Г., Кучук-Яценко С.І., Мальчевський І.А.,
Марченко О.А., Петров В.В., Пехньо В.І., Походенко В.Д., Прокопенко В.А., Рагуля А.В.,
Чехун В.Ф.

Програмний оргкомітет:

Крючин А.А., Різак В.М., Рубіш В.М., Студеняк І.П., Уваров В.М.

Локальний оргкомітет:

Рубіш В.М., Макар Л.І., Поп М.М., Ясінко Т.І., Коротун А.В.

National Academy of Sciences of Ukraine
Institute for Information Recording
Uzhgorod laboratory of optoelectronics and photonics materials of the Institute for
Information Recording
Technical center
Uzhgorod National University

School-conference of young scientists

MODERN MATERIAL SCIENCE: PHYSICS, CHEMISTRY, TECHNOLOGY
(MMSPT – 2021)

**Uzhgorod Vodogray Ukraine,
4 - 8 October 2021**

**PROGRAM & MATERIALS
OF THE CONFERENCE**

ONLINE VERSION

**Uzhgorod
2021**

УДК 536:669
ББК 34

EDITORIAL BOARD

EDITOR-IN CHIF

Naumovets' A.H.

DEPUTY EDITOR-IN CHIF

Kryuchyn A.A., Uvarov V.M.

EDITORIAL BOARD MEMBERS

Bespalov S.A., Malchevskii I.A., Pop M.M., Rubish V.M.

Published by the decision of the Organizing Committee of MMSPCT – 2021 and the Academic Council of the Institute for Information Recording NAS of Ukraine

Materials of the School-conference of young scientists «Modern material science: physics, chemistry, technology (MMSPCT – 2021)» – Uzhgorod: PE Sabov A.M. , Ukraine – 320 p.

The materials represent contents of invited lectures by leading Ukrainian and European scientists in the field of physics, chemistry and technology of new functional materials and conference's reports based on the results of fundamental and applied works in the field of modern material science on different directions: metals, alloys, ceramics and compositional materials; semiconductor, dielectric, magnetic and glassy materials; nanosystems, nanomaterials, nanotechnologies; dimensional effects, self-organization and modeling of nanostructures; films, coatings and surface nanosystems; biofunctional nanomaterials, nanosystems in biology and medicine; polymers, supramolecular structures, airgels, colloidal systems; technologies, diagnostics and applications of materials.

The edition is designed for scientists, engineers, higher school lecturers, post-graduates and students of corresponding specialities.

Organizing committee:

Chairmen:

Naumovets' A.H. (Kiev, Ukraine)

Co-Chairmens:

Kryuchyn A.A. (Kiev, Ukraine)

Uvarov V.M. (Kiev, Ukraine)

Secretary:

Rubish V.M. (Uzhgorod, Ukraine)

Beljaev O.E., Bepalov S.A., Brodin M.S., Chekhun V.F., Kartel M.T., Kladko V.P.,
Komisarenko S.V., Koshechko V.G., Kuchuk-Yatsenko S.I., Malchevskii I.A., Marchenko O.A.,
Pekhnyo V.I., Petrov V.V., Pokhodenko V.D., Prokopenko V.A., Ragulya A.V., Voevodin V.M.,
Vysochanskii Yu.M.

Program committee:

Kryuchyn A.A., Rizak V.M., Rubish V.M., Studenjak I.P., Uvarov V.M.

Local Organizing Committee:

Rubish V.M., Makar L.I., Pop M.M., Yasinko T.I., Korotun A.V.

Optical signals registration unit for fiber optic temperature sensor

Chychura Ig.I.,¹ Kutchak S.V.,¹ Chychura Iv.I.,² Oseafiana S.C.¹

¹National University of Uzhhorod, Uzhhorod, Ukraine,

²Institute of Electron Physics, Ukrainian National Academy of Sciences, Uzhhorod, Ukraine,

A special place among a significant number of fiber-optic sensors is occupied by temperature sensors (FOTS) with amplitude modulation of the optical signal at a certain wavelength. Such sensors, due to the simplicity of their design, reliability, reproducibility of results and satisfactory technical characteristics, as well as the possibility of application in areas of explosion hazard, are increasingly used in engineering and industry. The principle of operation of such sensors is based on the registration of the change in the transmission of the semiconductor sensing element at a fixed wavelength with temperature variation. In this regard, much attention is paid to a specialized device, which is designed for registration and priority analog processing of the information signal received by the FOTS. Since the cost of spectral complexes for the study of optical fibers is quite high, it is not technically feasible to determine the technical characteristics, testing and calibration of FOTS with sensitive elements based on semiconductor materials. Therefore, the task is to develop specialized recorders of information signals received from FOTS. This means that such a device must provide controlled light fluxes, which are generated and recorded by no inertial optoelectronic devices (LED, photodiode) and a progressive circuit for processing the optical signal obtained by FOTS with sensitive element.

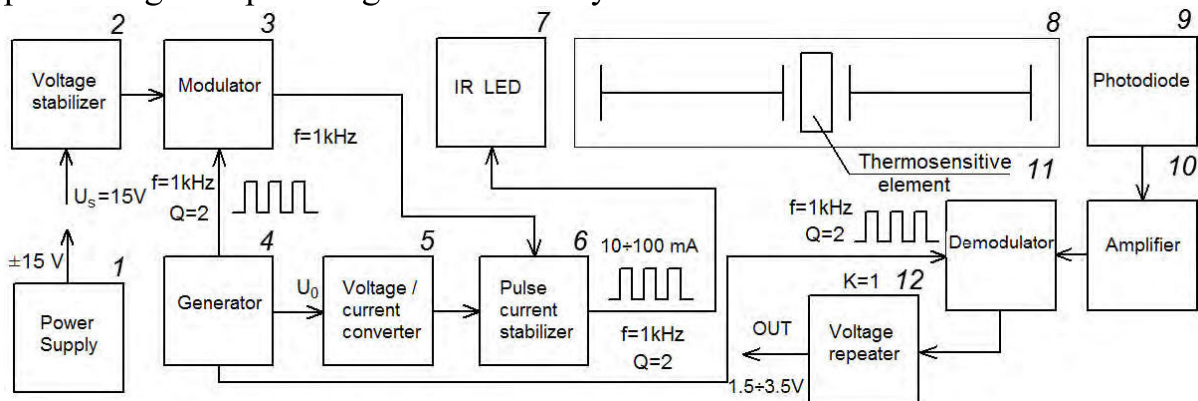


Fig.1. Combined block diagram of the optical electronic recorder of FOTS

We have proposed an innovative unit for analog processing of measuring information for FOTS with amplitude modulation of the optical signal. The scheme is based on the principle of non-traditional use of the integrated circuit $\mu A727M$, which is an element of the "modulator/demodulator" and protects the output signal from intermodulation interference, unauthorized illumination and the influence of multiplicative interference. The combined block diagram of the optoelectronic recorder is shown in Fig.1. It is conventionally divided into two parts: the emitter unit, which provides a modulated stabilized light flux, and the photo detector unit based on the amplifier and demodulator, which is connected via a fiber-optic connector to the FOTS.

The LED radiation modulation circuit consists of a modulator (3) built into the generator chip (4) and an input voltage stabilizer (2). The modulator is built on a pair of matched field-effect transistors and modulates (in amplitude) the input stabilized voltage with a frequency of $f_m = 1$ kHz ($Q = 2$). Pulses of modulated voltage of a given amplitude are fed to the converter "voltage/current" and pulse transistor current stabilizer (6). Voltage pulses with the same technical characteristics create at the output of the current stabilizer pulses, the amplitude of which can be modulated from 10 to 100 mA, which provide power to the selected LED (7), which serves the FOTS. The pulsed radiation of the LED passes through the fiber-optic path and, depending on the temperature, changes its amplitude at the output of the FOTS (8). The photodiode (9) detects the change of the optical signal. The amplifier (10) amplifies the amplitude to the required value for subsequent processing and supplies this signal to the demodulator. The demodulator converts this pulse signal at a frequency of 1 kHz synchronously and in phase with the key elements of the modulator (3). A key element of the demodulator are identical field-effect transistors that are used in the modulator, which ensures the synchrony and in-phase operation of the modulator and demodulator. As a result, the output of the demodulator is a constant component of the output information signal, which corresponds to the change in the transmission of FOTS with temperature variation. To provide a variety of output devices in the circuit included an additional operational voltage repeater, which provides a fairly good consistency of the input and output impedance. This allows us to use a variety of indicator devices from analog pointer voltmeters to modern analog-to-digital converter, including those that are part of microcontrollers.

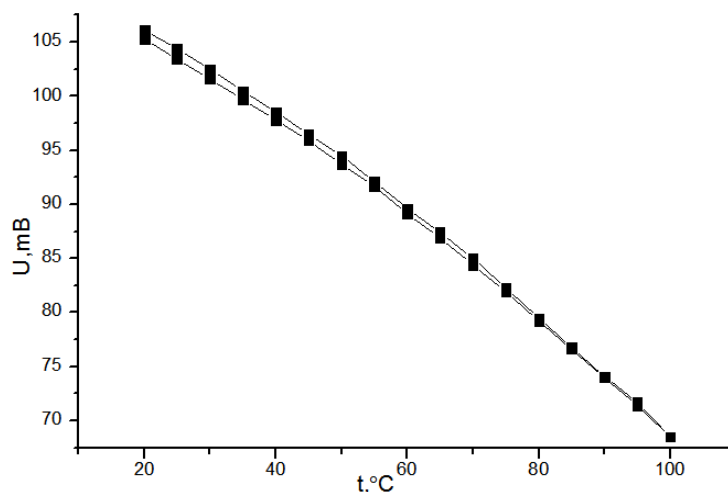


Fig.2. Dependence of the voltage at the output of the FOTS circuit from the temperature of thermosensitive element.

Fig. 2 shows the results of temperature measurement for sensitive element based on $As_{45}Se_{55}$ ($\lambda_0 = 808$ nm), which were obtained using an experimental model of the described recorder. During the measurement, the thermosensitive element was heated to a temperature of 100 ° C and then cooled to room temperature. A small deviation of the heating and cooling curve (maximum difference of about 1.5 mV) may be due to changes in the optical properties of the material.